

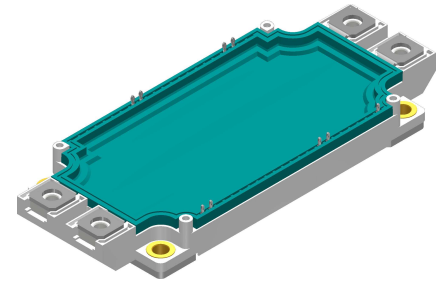
Standard Rectifier Module

$V_{RRM} = 2 \times 1600 \text{ V}$
 $I_{FAV} = 600 \text{ A}$
 $V_F = 1.2 \text{ V}$


Phase leg + NTC

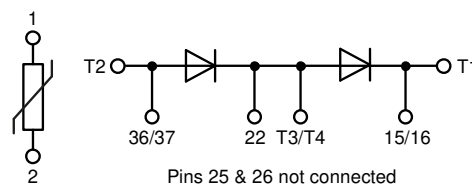
Part number

MDMA600P1600PTSF



Backside: isolated

 E72873



Features / Advantages:

- Package with DCB ceramic
- Improved temperature and power cycling
- Planar passivated chips
- Very low forward voltage drop
- Very low leakage current

Applications:

- Diode for main rectification
- For single and three phase bridge configurations
- Supplies for DC power equipment
- Input rectifiers for PWM inverter
- Battery DC power supplies
- Field supply for DC motors

Package: SimBus F

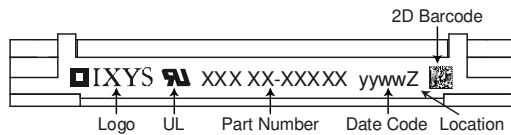
- Isolation Voltage: 4300 V~
- Industry standard outline
- RoHS compliant
- PressFit-Pins for PCB mounting
- Height: 17 mm
- Base plate: Copper internally DCB isolated
- Advanced power cycling
- Phase Change Material available

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Rectifier				Ratings			
Symbol	Definition	Conditions		min.	typ.	max.	Unit
V_{RSM}	max. non-repetitive reverse blocking voltage					1700	V
V_{RRM}	max. repetitive reverse blocking voltage					1600	V
I_R	reverse current	$V_R = 1600$ V		$T_{VJ} = 25^\circ\text{C}$		400	μA
		$V_R = 1600$ V		$T_{VJ} = 150^\circ\text{C}$		10	mA
V_F	forward voltage drop	$I_F = 600$ A		$T_{VJ} = 25^\circ\text{C}$		1.26	V
		$I_F = 1200$ A				1.60	V
		$I_F = 600$ A		$T_{VJ} = 125^\circ\text{C}$		1.20	V
		$I_F = 1200$ A				1.61	V
I_{FAV}	average forward current	$T_C = 100^\circ\text{C}$		$T_{VJ} = 150^\circ\text{C}$		600	A
		rectangular	d = 0.5				
V_{FO}	threshold voltage			$T_{VJ} = 150^\circ\text{C}$		0.78	V
r_F	slope resistance					0.67	m Ω
		} for power loss calculation only					
R_{thJC}	thermal resistance junction to case					0.05	K/W
R_{thCH}	thermal resistance case to heatsink				0.03		K/W
P_{tot}	total power dissipation			$T_C = 25^\circ\text{C}$		2500	W
I_{FSM}	max. forward surge current	t = 10 ms; (50 Hz), sine		$T_{VJ} = 45^\circ\text{C}$		15.0	kA
		t = 8,3 ms; (60 Hz), sine		$V_R = 0$ V		16.2	kA
		t = 10 ms; (50 Hz), sine		$T_{VJ} = 150^\circ\text{C}$		12.8	kA
		t = 8,3 ms; (60 Hz), sine		$V_R = 0$ V		13.8	kA
I^2t	value for fusing	t = 10 ms; (50 Hz), sine		$T_{VJ} = 45^\circ\text{C}$		1.13	MA ² s
		t = 8,3 ms; (60 Hz), sine		$V_R = 0$ V		1.09	MA ² s
		t = 10 ms; (50 Hz), sine		$T_{VJ} = 150^\circ\text{C}$		812.8	kA ² s
		t = 8,3 ms; (60 Hz), sine		$V_R = 0$ V		788.8	kA ² s
C_J	junction capacitance	$V_R = 400$ V; f = 1 MHz		$T_{VJ} = 25^\circ\text{C}$		661	pF

Package SimBus F		Ratings				
Symbol	Definition	Conditions	min.	typ.	max.	Unit
I_{RMS}	RMS current	per terminal			tbd	A
T_{VJ}	virtual junction temperature		-40		175	°C
T_{op}	operation temperature		-40		150	°C
T_{stg}	storage temperature		-40		125	°C
Weight				350		g
M_D	mounting torque		3		6	Nm
M_T	terminal torque		3		6	Nm
$d_{Spp/App}$	creepage distance on surface striking distance through air	terminal to terminal	13.3	10.0		mm
$d_{Spb/Apb}$		terminal to backside	10.2	10.2		mm
V_{ISOL}	isolation voltage	t = 1 second		4300		V
		t = 1 minute	50/60 Hz, RMS; $I_{ISOL} \leq 1$ mA	3600		V


Part description

M = Module
 D = Diode
 M = Standard Rectifier
 A = (up to 1800V)
 600 = Current Rating [A]
 P = Phase leg
 1600 = Reverse Voltage [V]
 PT = PressFit-Pin, Thermistor
 SF = SimBus F
 - = Hyphen
 PC = Phase Change Material

Ordering	Ordering Number	Marking on Product	Delivery Mode	Quantity	Code No.
Standard	MDMA600P1600PTSF	MDMA600P1600PTSF	Blister	24	519071
Alternative	MDMA600P1600PTSF-PC	MDMA600P1600PTSF	Blister	24	519064

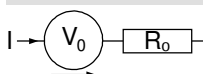
Similar Part	Package	Voltage class
MDMA300P1600PTSF	SimBus F	1600
MDMA425P1600PTSF	SimBus F	1600
MDNA300P2200PTSF	SimBus F	2200
MDNA425P2200PTSF	SimBus F	2200

Temperature Sensor NTC

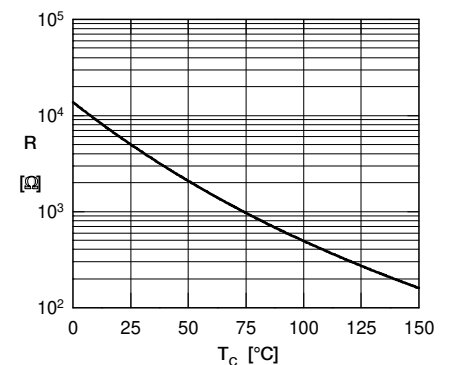
Symbol	Definition	Conditions	min.	typ.	max.	Unit
R_{25}	resistance	$T_{VJ} = 25^\circ$	4.85	5	5.15	k Ω
$B_{25/50}$	temperature coefficient			3375		K

Equivalent Circuits for Simulation

* on die level

 $T_{VJ} = 150^\circ\text{C}$


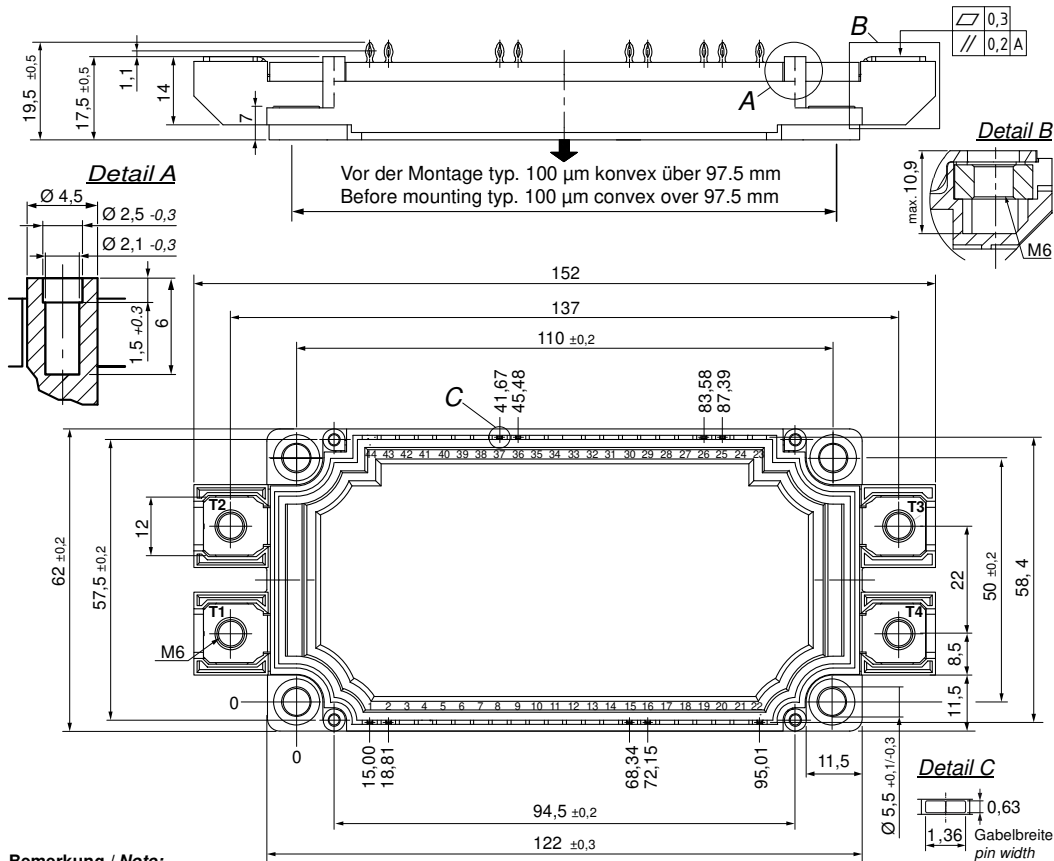
$V_{0\ max}$	threshold voltage	0.78				V
$R_{0\ max}$	slope resistance *	0.15				m Ω



Typ. NTC resistance vs. temperature



Outlines SimBus F

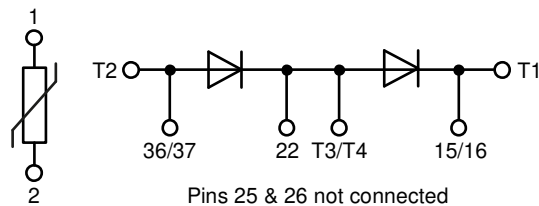


Bemerkung / Note:

- Nichttolerierete Maße nach / Measure w/o tolerances acc. DIN ISO 2768-T1-m
- PCB-Lochmuster / PCB hole pattern: see pin position
- Toleranz Pin-Position und PCB-Lochmuster / Tolerance of pin position and PCB hole pattern: $\oplus 0,1$
- Bohrlochdurchmesser / Diameter of drill: $\varnothing 1,16$ mm
- Endlochdurchmesser / Diameter of plated holes: $\varnothing 1,00 - 1,10$ mm (Cu thickness in via typ. 50 μm)
- Beschichtung / Plating: chem. Sn max. 15 μm
- Einpresskraft / Insert Force: per terminal with a typ. insert speed of 1 mm/s: typ. 90 N
- Weitere Angaben / Further information: www.ixys.com Application note IXAN0077
- Montageanleitung / Mounting instruction: www.ixys.com Application note IXAN0024

Detail A: PCB-Montage / Mounting on PCB^L

- Empfohlene, selbstschneidende Schraube / Recommended, self-tapping screw: **EJOT PT®** (Größe / size: **K25**)^L
- Max. Schraubenlänge / Max. screw length: **PCB-Dicke / thickness + 6 mm** (max. Lochtiefe / hole depth)^L
- Empfohlenes Drehmoment / Recommended mounting torque: **1.5 Nm**



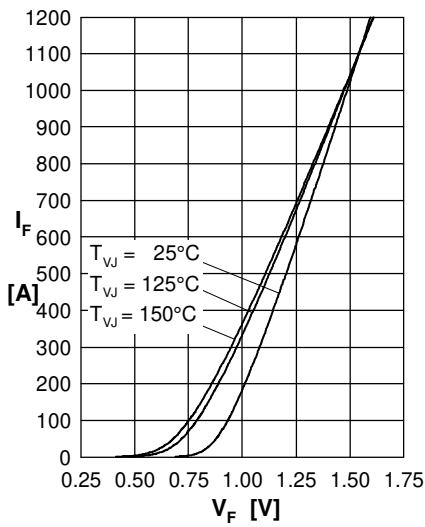
Rectifier


Fig. 1 Forward current versus voltage drop per diode

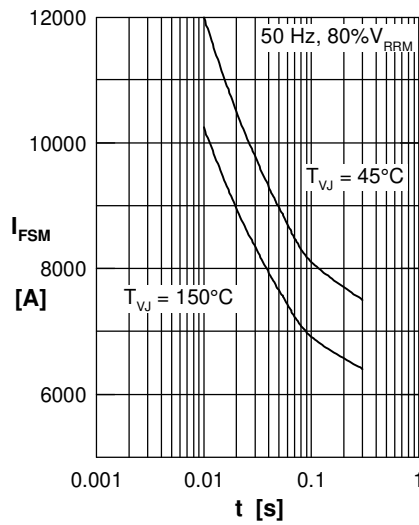


Fig. 2 Surge overload current vs. time per diode

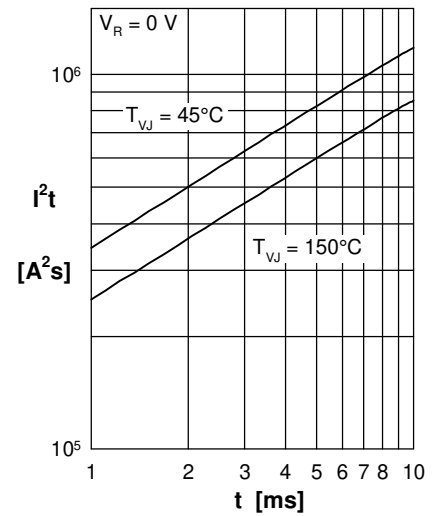
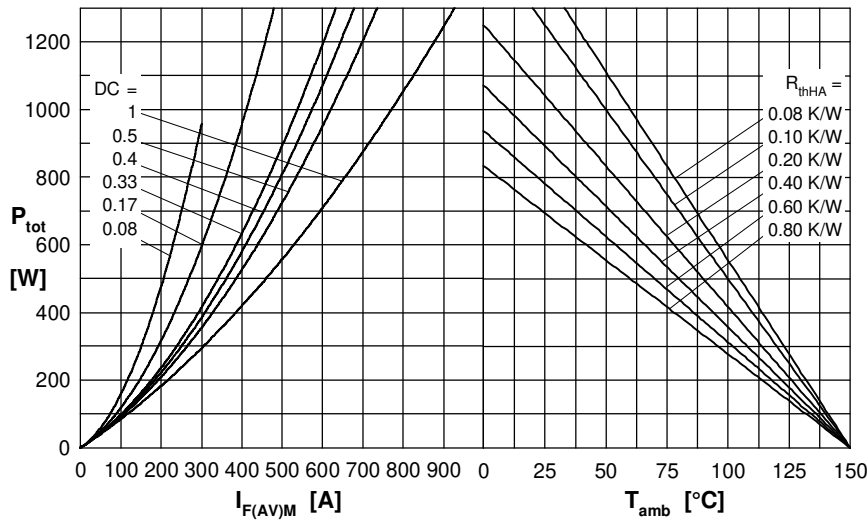

 Fig. 3 I^2t versus time per diode


Fig. 4 Power dissipation vs. forward current and ambient temperature per diode

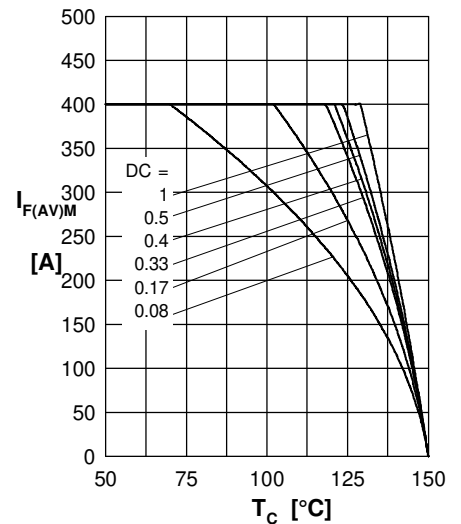


Fig. 5 Max. forward current vs. case temperature per diode

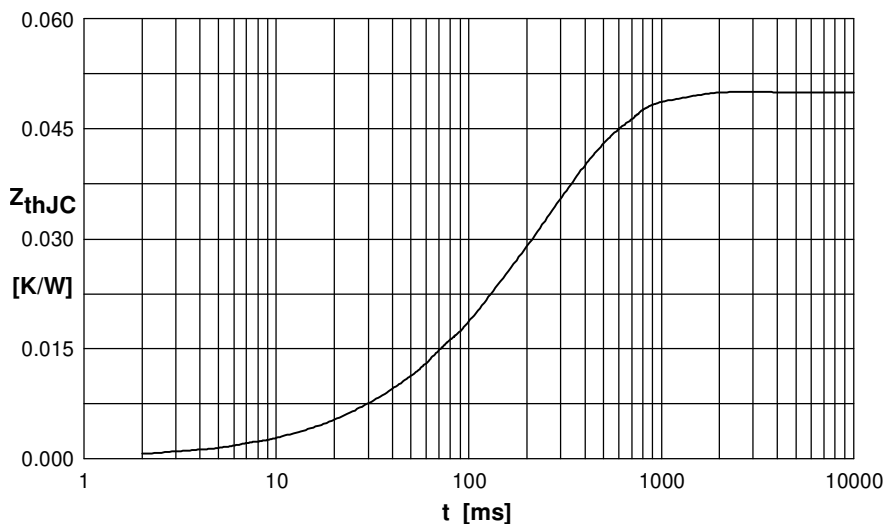


Fig. 6 Transient thermal impedance junction to case vs. time per diode

 Constants for Z_{thJC} calculation:

i	R_{thi} (K/W)	t_i (s)
1	0.002	0.0150
2	0.008	0.0800
3	0.013	0.2200
4	0.037	0.3800